

PNP TRANSISTOR WITH DUAL SERIES SWITCHING DIODE

Features

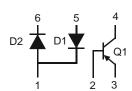
- Integrates one PNP Transistor (Q1) and two Switching Diodes (D1, D2) in a Single Compact Package
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

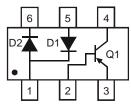
- Case: SOT26
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Copper Leadframe (Lead-Free Plating). Solderable per MIL-STD-202, Method 208 <a> § 3
- Terminal Connections: See Diagram
- Weight: 0.01 grams (Approximate)







Device Schematic



Top View Pin Configuration

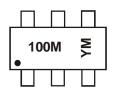
Ordering Information (Note 4)

Part Number	Case	Packaging
DSM80100M-7	SOT26	3,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



100M = Product Type Marking Code (See Electrical Characteristics Table) YM = Date Code Marking Y = Year (ex: B = 2014) M = Month (ex: 9 = September)

Date Code Key

Year	201	4	2015		2016	20	17	2018		2019	2	2020
Code	В		С		D	E		F		G		I
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings - Q1 (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-80	V
Collector-Emitter Voltage	V _{CEO}	-80	V
Emitter-Base Voltage	V _{EBO}	-4.0	V
Continuous Collector Current	I _{C(MAX)}	-500	mA
Peak Pulse Collector Current @ DC Increment for I _C ;	lau	-1.0	Δ
I _B = 300mA; test duration >10s for each step.	ICM	-1.0	^
Base Current	I _B	-200	mA

$\hline \textbf{Maximum Ratings - D1,} \ \ \textbf{D2} \ (@T_A = +25 ^{\circ}\text{C}, \text{ unless otherwise specified.})$

Characteristic	Symbol	Value	Unit
Non-Repetitive Peak Reverse Voltage	V_{RM}	100	V
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	75	V
RMS Reverse Voltage	V _{R(RMS)}	53	V
Forward Continuous Current (Note 5)	I _{FM}	300	mA
Average Rectified Output Current (Note 5)	lo	200	mA
Non-Repetitive Peak Forward Surge Current @ t = 1.0µs	I _{FSM}	20	A

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P_{D}	600	mW
Thermal Resistance, Junction to Ambient Air (Note 5)	$R_{ hetaJA}$	208	°C/W
Operating and Storage Temperature Range	$T_{J_i}T_{STG}$	-65 to +150	°C

Electrical Characteristics – Q1 (@T_A = +25°C, unless otherwise specified.)

Characteristic (Note 6)	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-80	_	_	V	$I_C = -100\mu A, I_E = 0$
Collector-Emitter Breakdown Voltage	BV _{CEO}	-80	_	_	V	$I_C = -1.0 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	BV _{EBO}	-4	_	_	V	$I_E = -100 \mu A, I_C = 0$
Collector Cutoff Current	I _{CBO}	_	_	-100	nA	$V_{CB} = -60V, I_E = 0$
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	_	-0.25	V	$I_C = -100 \text{mA}, I_B = -10 \text{mA}$
DC Current Transfer Ratio	h _{FE}	120	280	500		$I_C = -10 \text{mA}, \ V_{CE} = -1.0 \text{V}$

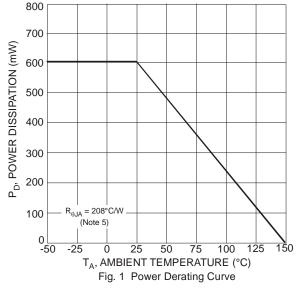
Electrical Characteristics - D1, D2 (@TA = +25°C, unless otherwise specified.)

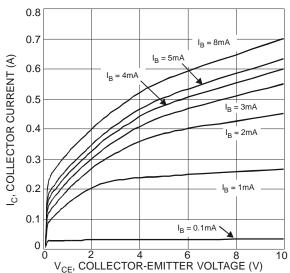
Characteristic	Symbol	Min	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 6)	$V_{(BR)R}$	75	_	V	$I_R = 100\mu A$
		_	0.715	V	$I_F = 5.0 \text{mA}$
Forward Voltage	\/_	_	0.855		$I_F = 10mA$
o waru voltage	VF	_	1.0		$I_F = 50mA$
		_	1.25		I _F = 150mA
Leakage Current (Note 6)	I _R	_	0.1	μA	V _R = 75V
Leakage Current (Note o)		_	25	nA	V _R = 20V
Total Capacitance	Ст	_	1.5	pF	V _R = 0V, f = 1.0MHz
Reverse Recovery Time	t _{rr}		4	1 ns	$I_F = I_R = 10 \text{mA},$
Travalation (Control of Trans			_		$I_{rr} = 0.1 \text{ x } I_{R}, R_{L} = 100\Omega$

Notes: 5. Device mounted on FR-4 PC board with recommended pad layout, which can be found on our website at http://www.diodes.com.

6. Short duration pulse test used to minimize self-heating effect.







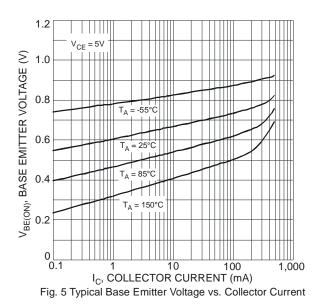


Fig. 3 Typical Collector Current vs. Collector-Emitter Voltage

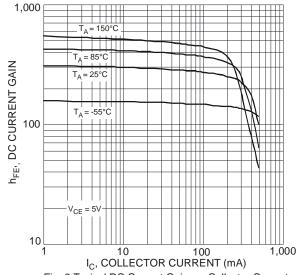


Fig. 2 Typical DC Current Gain vs. Collector Current

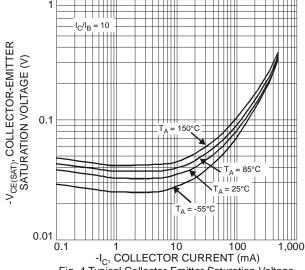
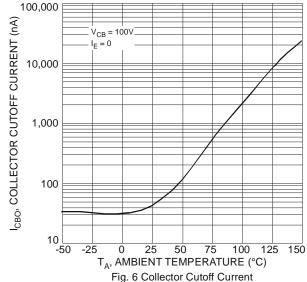
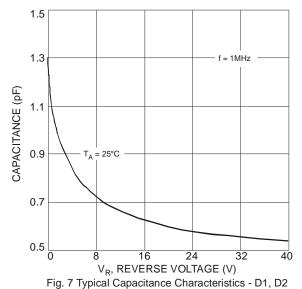
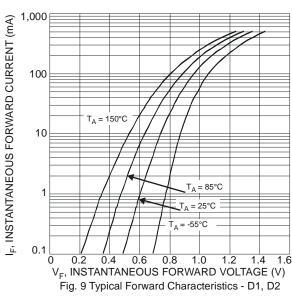


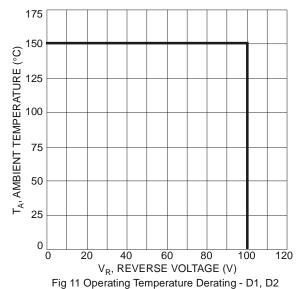
Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

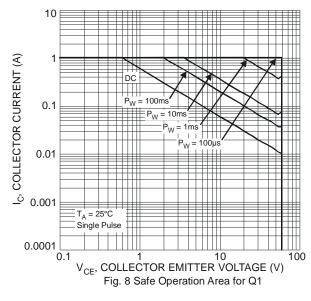


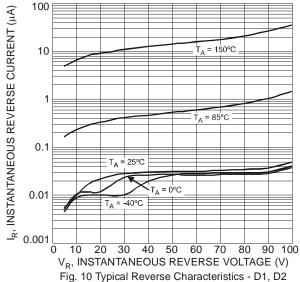








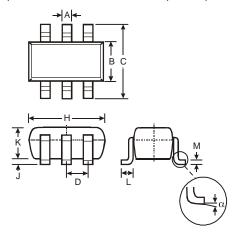






Package Outline Dimensions

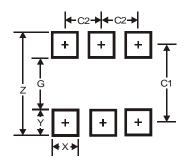
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



	SOT26						
Dim	Min	Max	Тур				
Α	0.35	0.50	0.38				
В	1.50	1.70	1.60				
С	2.70	3.00	2.80				
D	_	_	0.95				
Н	2.90	3.10	3.00				
J	0.013	0.10	0.05				
K	1.00	1.30	1.10				
L	0.35	0.55	0.40				
M	0.10	0.20	0.15				
α	0°	8°	_				
All D	All Dimensions in mm						

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	3.20
G	1.60
Х	0.55
Υ	0.80
C1	2.40
C2	0.95



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